

**Supplementary Information**  
**for**  
**Unseeded Hydroxide-Mediated Synthesis and CO<sub>2</sub> Adsorption Properties of**  
**an Aluminosilicate Zeolite with the RTH Topology**

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## Structural Characterization

The synchrotron powder X-ray diffraction (XRD) data were recorded on the beamline 9B at the Pohang Acceleration Laboratory (Pohang, Korea) using monochromated radiation with  $\lambda = 1.4865 \text{ \AA}$ . The detector arm of the vertical scan diffractometer consists of seven sets of Soller slits, flat Ge(111) crystal analyzers, anti-scatter baffles, and scintillation detectors, with each set separated by  $20^\circ$ . Data were collected at room temperature in flat plate mode, with a step size of  $0.01^\circ$  and overlaps of  $2^\circ$  to the next detector bank over the  $2\theta$  range  $5.0 - 125.5^\circ$ . The pattern was successfully indexed as monoclinic, with  $a = 9.744$ ,  $b = 20.744$ ,  $c = 9.883 \text{ \AA}$ ,  $\beta = 96.64^\circ$ , using the program NTREOR,<sup>S1</sup> as implemented in EXPO2009,<sup>S2</sup> and the systematic absences were compatible with the  $C2/m$  space group. Rietveld refinement was performed in GSAS<sup>S3</sup> using the EXPGUI interface<sup>S4</sup> with a model consistent with the RTH structure type but with the above cell parameters and starting with only Si and O. Initially, a fixed shifted Chebyshev function with 20 terms was used to model the background. After refining the scale factor, unit cell, zero shift and profile terms (pseudo-Voigt function type 4),<sup>S3</sup> the Si and O positions were refined under soft distance restraints (Si-O  $1.61 \text{ \AA}$  and nonbonding O-O  $2.61 \text{ \AA}$  distances within tetrahedra, initially with a relatively heavy weight). Difference Fourier analysis revealed at this point an interesting feature with the shape of a quadrangular torus inside the cavity. Then, a rigid-body cation (centered on a dummy H at the gravity center) was introduced to model the organic structure-directing agent (OSDA). No real hydrogen atom was included and, instead, the occupancy factors of CH and CH<sub>3</sub> groups were adjusted to account for the total number of electrons.<sup>S5</sup> This approach produced high atomic displacement parameters in the final model to compensate for the more spread electronic density of the CH and CH<sub>3</sub> groups. The starting position was close to but a little off the center of the cavity in the  $xy$  plane, and the occupancy was halved to account for the two cations per cavity (four per unit cell) found by elemental analysis. Upon refining its position, the cation moved away from the described position and took a conformation that, considering the four symmetric cations, closely matched the above mentioned torus. Attempts to refine the structure in space groups  $Cm$  or  $C2$  failed (in  $Cm$  the two cations formed a corner of the referred quadrangular torus, implying collision (because of the full occupancy of sites), and leaving the opposite side of the cavity deficient in electronic density; in  $C2$  the cations have a more logical parallel arrangement, similar to that found in  $C/2m$ , but the refinement could not be made to converge). Then, the distance restraints were gradually relaxed. Al was introduced at the same positions as Si with fractional occupancies of 0.0909 and 0.9091, respectively, to account for the overall Si/Al ratio of 10, determined by elemental analysis. Al and Si at each position were forced to move together. The restraints were further relaxed and the background was also refined, before the isotropic atomic displacement parameters were also introduced in the refinement (for the OSDA cation these parameters were refined in groups: CH<sub>3</sub>, CH, and N1-C2-

N3). Finally, the restrains were completely eliminated. No preferential occupation by Al could be proven or disproven. Crystallographic data are collected in Table S1 and atomic parameters in Table S2. While the values of the residuals are reasonably good, the reduced  $\chi^2$  is uncomfortably high (8.882) and the Rietveld plot shows relatively large discrepancies between the calculated and experimental patterns (Figure S4). The disagreements are related to the shape of the peaks which have very long tails and narrow full-widths at half-maximums (fwhm), together with a strong asymmetry, and could not be modelled any better using other profile functions available in GSAS. Thus, a model independent Le Bail type whole profile fitting was undertaken in GSAS, refining the same number and type of non-structural parameters, plus the cell parameters. The resulting  $\chi^2$  was also relatively high (5.508) and, furthermore, exactly the same type of disagreement between the calculated and experimental patterns were observed (Figure S5), suggesting the relatively high  $\chi^2$  values are actually due to the difficulty in modelling the peak shape (long tails and asymmetry) of the high quality synchrotron data.<sup>S6</sup>

## References

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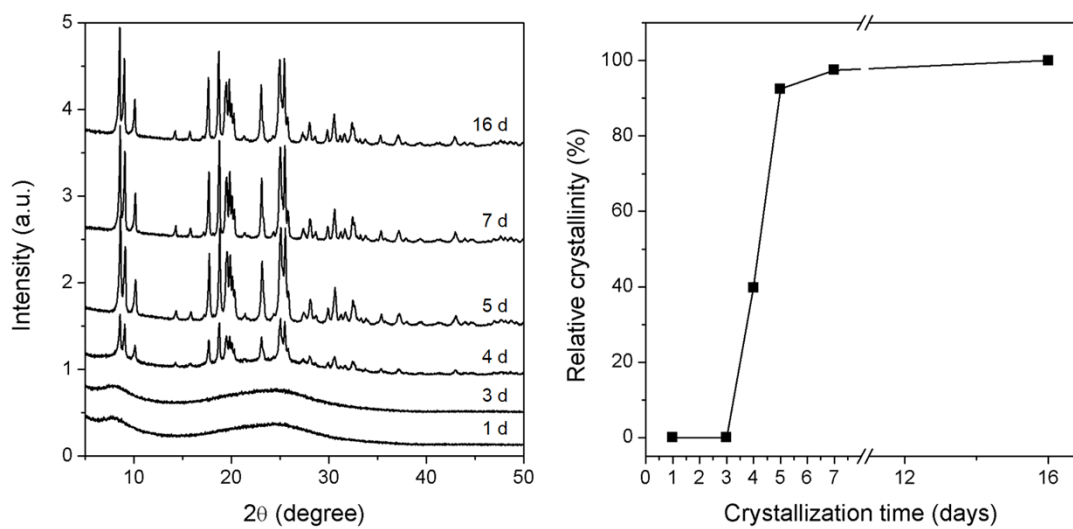
**Table S1** Crystallographic and experimental parameters for the Rietveld refinement of as-made 123TMI-RTH.

|                               |             |
|-------------------------------|-------------|
| wavelength (Å)                | 1.4865      |
| temperature (K)               | 293         |
| 2 $\theta$ range              | 5.00-125.50 |
| no. of data points            | 12051       |
| no. of reflections            | 1844        |
| space group                   | <i>C2/m</i> |
| unit cell parameters (Å)      |             |
| <i>a</i>                      | 9.74697(25) |
| <i>b</i>                      | 20.7517(5)  |
| <i>c</i>                      | 9.88360(23) |
| $\beta$                       | 96.6492(12) |
| cell volume (Å <sup>3</sup> ) | 1985.67(13) |
| residuals                     |             |
| $R_{wp}$                      | 8.95        |
| $R_p$                         | 6.98        |
| $R_F^2$                       | 6.391       |
| reduced $\chi^2$              | 8.882       |

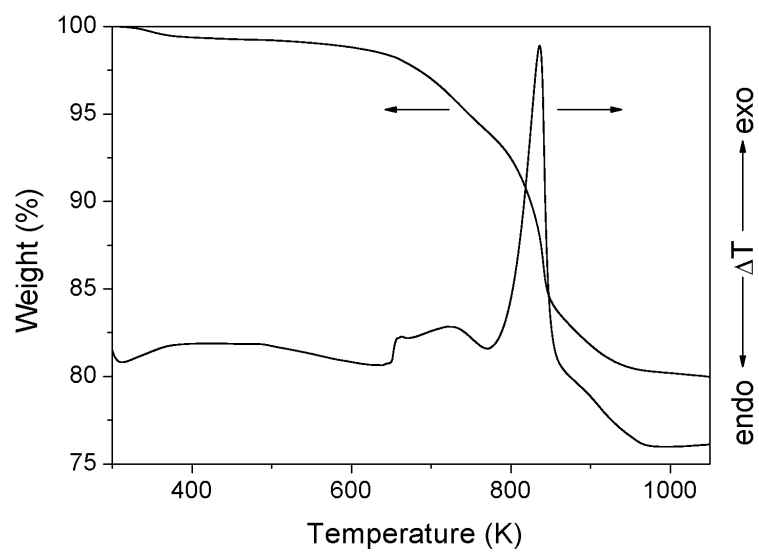
**Table S2** Fractional atomic coordinates, isotropic displacement parameters, and fractional occupancies for as-made 123TMI-RTH in space group  $C2/m$ .

| atom | $x$      | $y$     | $z$      | $U_{\text{iso}}(\times 100)$ | occupancy <sup>a</sup> |
|------|----------|---------|----------|------------------------------|------------------------|
| Si1  | 0.25527  | 0.23487 | 0.71954  | 1.83                         | 0.90910                |
| Al1  | 0.25527  | 0.23487 | 0.71954  | 1.83                         | 0.09090                |
| Si2  | 0.08587  | 0.07630 | 0.37912  | 2.08                         | 0.90910                |
| Al2  | 0.08587  | 0.07630 | 0.37912  | 2.08                         | 0.09090                |
| Si3  | 0.34613  | 0.15409 | 0.48912  | 2.11                         | 0.90910                |
| Al3  | 0.34613  | 0.15409 | 0.48912  | 2.11                         | 0.09090                |
| Si4  | 0.49993  | 0.31974 | 0.83947  | 1.67                         | 0.90910                |
| Al4  | 0.49993  | 0.31974 | 0.83947  | 1.67                         | 0.09090                |
| O1   | 0.30069  | 0.17557 | 0.62818  | 1.37                         | 1.00000                |
| O2   | 0.50000  | 0.33399 | 1.00000  | 0.76                         | 1.00000                |
| O3   | 0.09392  | 0.00000 | 0.32384  | 3.42                         | 1.00000                |
| O4   | 0.25729  | 0.09493 | 0.43283  | 2.43                         | 1.00000                |
| O5   | 0.50000  | 0.12735 | 0.50000  | 3.44                         | 1.00000                |
| O6   | 0.37524  | 0.26811 | 0.80525  | 3.91                         | 1.00000                |
| O7   | 0.14462  | 0.21240 | 0.82294  | 2.93                         | 1.00000                |
| O8   | 0.17174  | 0.28534 | 0.61129  | 2.75                         | 1.00000                |
| O9   | 0.47451  | 0.38305 | 0.75681  | 3.80                         | 1.00000                |
| O10  | 0.00000  | 0.08903 | 0.50000  | 1.48                         | 1.00000                |
| N1   | 0.01254  | 0.41493 | 0.11548  | 10.62                        | 0.50000                |
| C5   | 0.04181  | 0.37827 | 0.00411  | 28.50                        | 0.58333                |
| C4   | 0.16232  | 0.39948 | -0.03071 | 28.50                        | 0.58333                |
| N3   | 0.20630  | 0.44904 | 0.05955  | 10.62                        | 0.50000                |
| C2   | 0.11367  | 0.45737 | 0.14692  | 10.62                        | 0.50000                |
| C6   | -0.11312 | 0.40596 | 0.18408  | 24.03                        | 0.75000                |
| C7   | 0.33716  | 0.48431 | 0.05185  | 24.03                        | 0.75000                |
| C8   | 0.11829  | 0.50498 | 0.26080  | 24.03                        | 0.75000                |

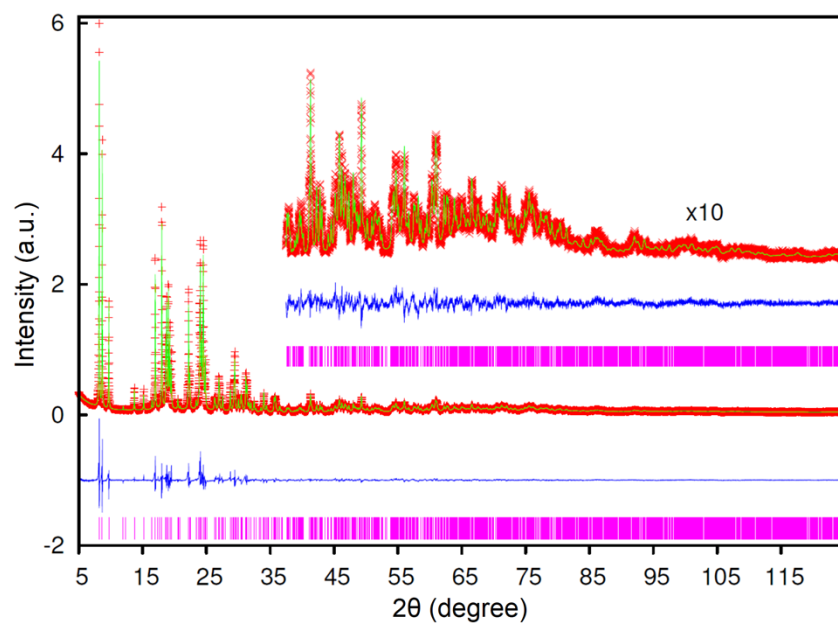
<sup>a</sup> Not refined.



**Fig. S1** Powder XRD patterns (left) and relative crystallinities (right) for a series of solid products obtained after crystallization using 123TMI<sup>+</sup> and Na<sup>+</sup> ions at Si/Al = 10 for different times.

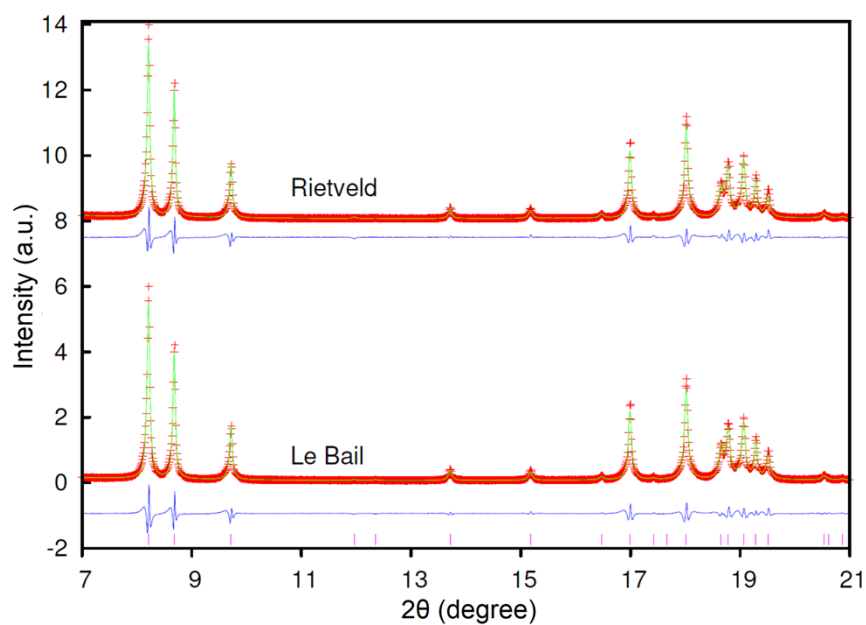


**Fig. S2** TGA/DTA curves of as-made RTH.

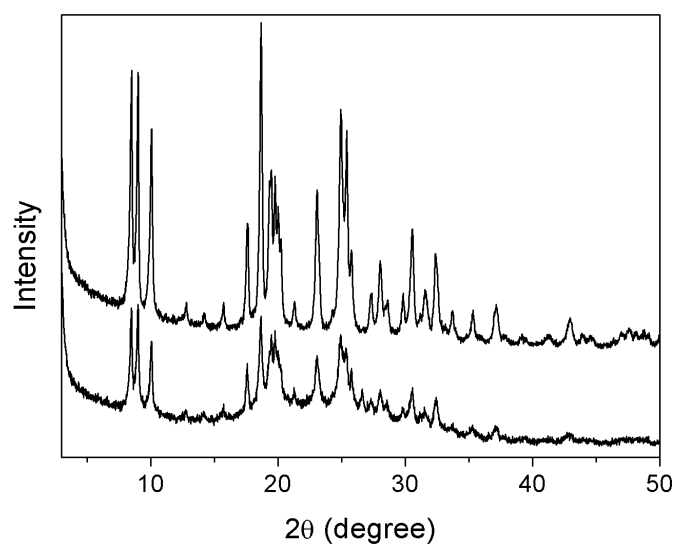


**Fig. S3** Rietveld plot for as-made 123TMI-RTH. Experimental (crosses), calculated (solid line), and difference plot (lower trace). The tick marks represent the positions of allowed reflections ( $\lambda = 1.48650 \text{ \AA}$ ).

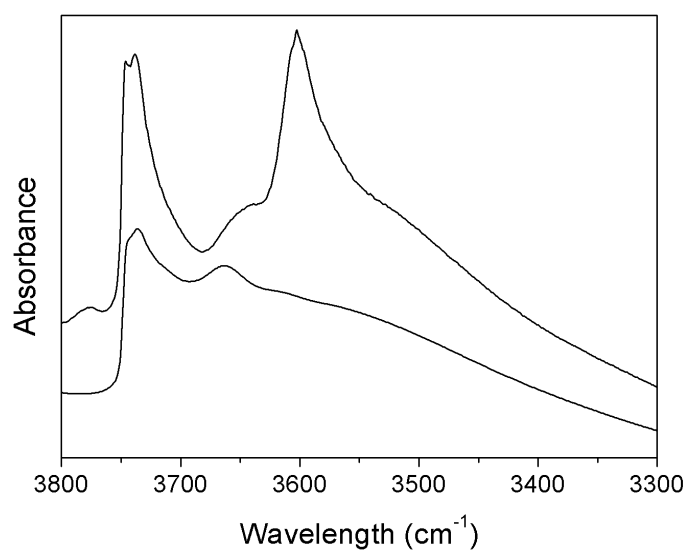




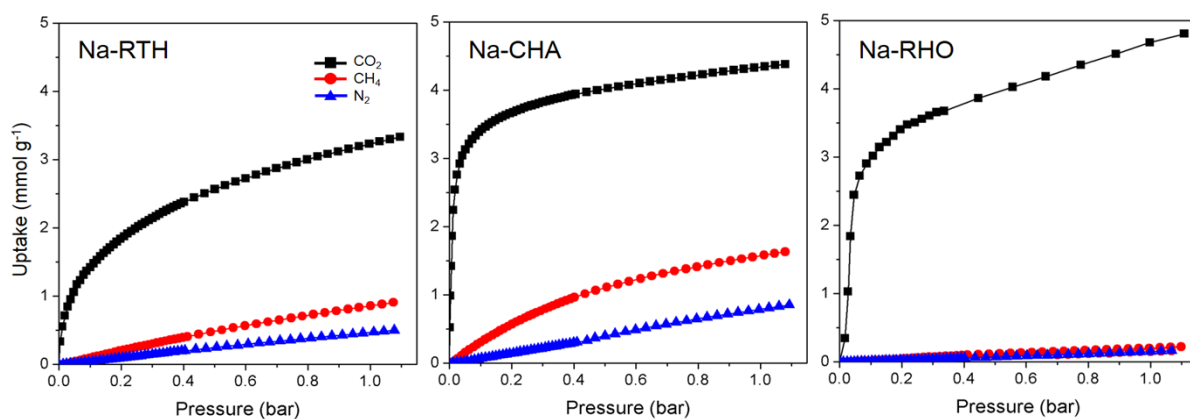
**Fig. S4** Comparison between Rietveld and Le Bail plots for as-made 123TMI-RTH. Experimental (crosses), calculated (solid line), and difference plot (lower trace). The tick marks represent the positions of allowed reflections ( $\lambda = 1.48650 \text{ \AA}$ ).



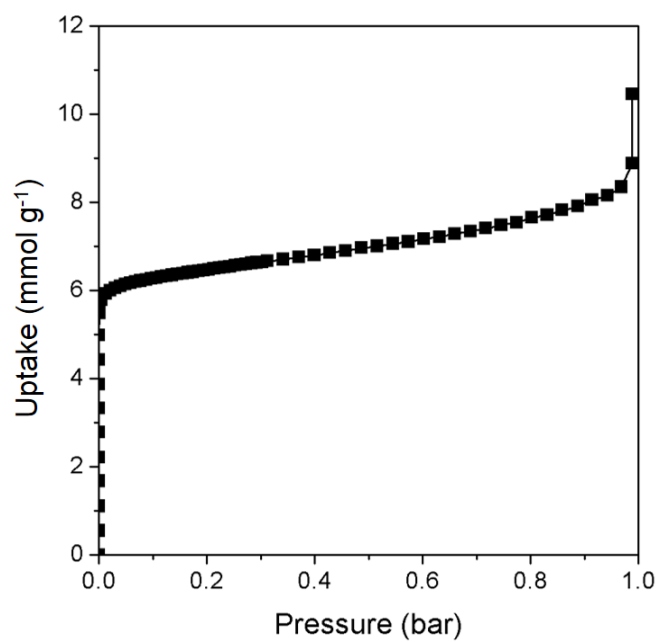
**Fig. S5** XRD patterns of fresh (top) and hydrothermally aged (bottom; at 1023 K for 24 h with flowing air containing 10% H<sub>2</sub>O) Cu-RTH.



**Fig. S6** IR spectra in the OH stretching region of H-RTH (top) and Na-RTH (bottom).



**Fig. S7** CO<sub>2</sub>, CH<sub>4</sub>, and N<sub>2</sub> adsorption isotherms at 298 K of Na-RTH, Na-CHA, and Na-RHO (from left to right).



**Fig. S8** N<sub>2</sub> adsorption isotherm of Na-RTH at 77 K.